



## Digital transistors (built-in resistors)

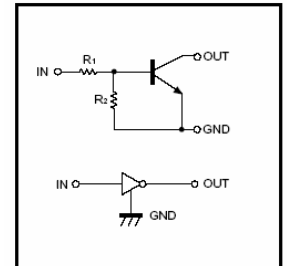
### DTC114YE/DTC114YUA /DTC114YKA/DTC114YSA/DTC114YCA

DIGITAL TRANSISTOR (NPN)

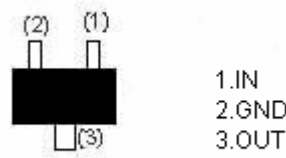
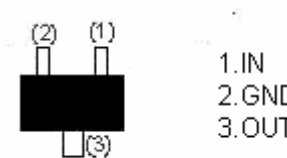
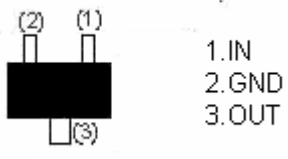
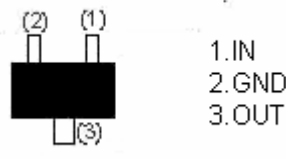
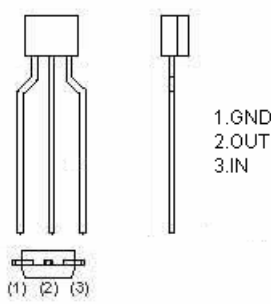
#### FEATURES

1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

#### ●Equivalent circuit



#### PIN CONNENCTIONS AND MARKING

<p>DTC114YE</p>  <p>1.IN 2.GND 3.OUT</p> <p>SOT-523      Abbreviated symbol: 64</p>	<p>DTC114YUA</p>  <p>1.IN 2.GND 3.OUT</p> <p>SOT-323      Abbreviated symbol: 64</p>
<p>DTC114YKA</p>  <p>1.IN 2.GND 3.OUT</p> <p>SOT-23-3L      Abbreviated symbol: 64</p>	<p>DTC114YCA</p>  <p>1.IN 2.GND 3.OUT</p> <p>SOT-23      Abbreviated symbol: 64</p>
<p>DTC114YSA</p>  <p>1.GND 2.OUT 3.IN</p> <p>TO-92S</p>	

### Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTC114Y□ )					Unit
		E	UA	KA	CA	SA	
Supply voltage	V <sub>CC</sub>	50					V
Input voltage	V <sub>IN</sub>	-6to+40					V
Output current	I <sub>o</sub>	70					mA
	I <sub>C(Max.)</sub>	100					mA
Power dissipation	P <sub>C</sub>	150	200			300	mW
Junction temperature	T <sub>j</sub>	150					°C
Storage temperature	T <sub>stg</sub>	-55 to+ 150					°C

### Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>			0.3	V	V <sub>CC</sub> =5V ,I <sub>o</sub> =100μA
	V <sub>I(on)</sub>	1.4				V <sub>O</sub> =0.3V ,I <sub>o</sub> =1mA
Output voltage	V <sub>O(on)</sub>			0.3	V	I <sub>o</sub> /I <sub>i</sub> =5mA/0.25mA
Input current	I <sub>i</sub>			0.88	mA	V <sub>I</sub> =5V
Output current	I <sub>o(off)</sub>			0.5	μA	V <sub>CC</sub> =50V ,V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	68				V <sub>O</sub> =5V ,I <sub>o</sub> =5mA
Input resistance	R <sub>1</sub>	7	10	13	KΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	3.7	4.7	5.7		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>O</sub> =10V ,I <sub>o</sub> =5mA,f=100MHz

### Typical Characteristics

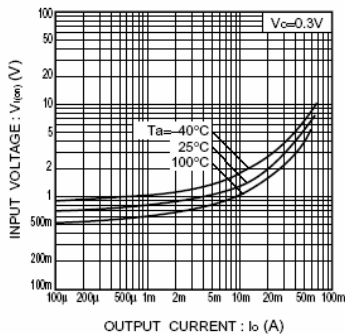


Fig.1 Input voltage vs. output current (ON characteristics)

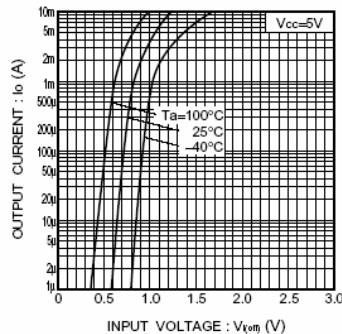


Fig.2 Output current vs. input voltage (OFF characteristics)

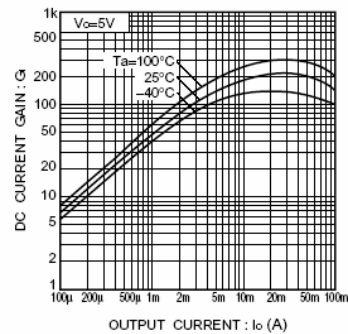


Fig.3 DC current gain vs. output current

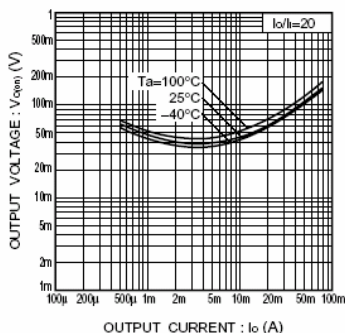


Fig.4 Output voltage vs. output current